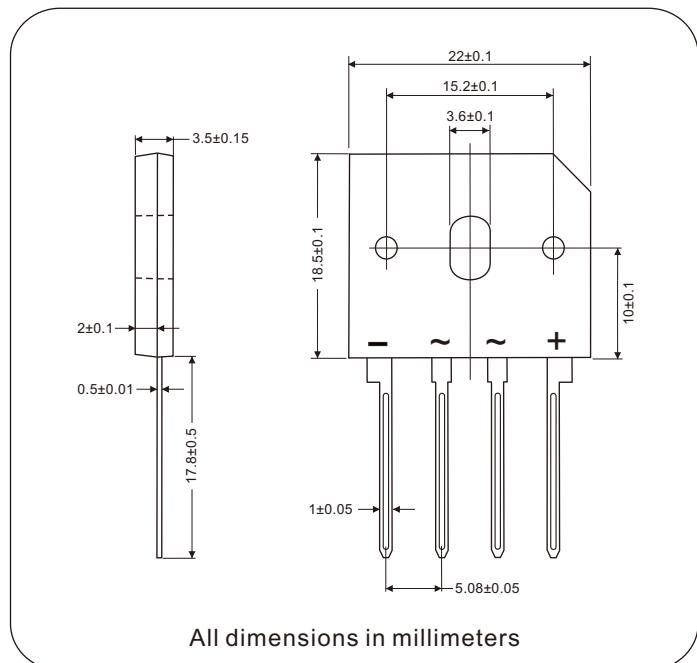
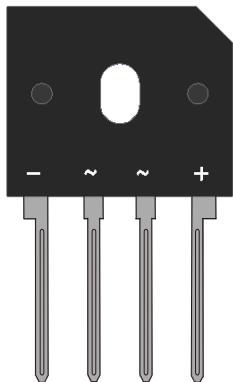


Glass Passivated Single-Phase Bridge Rectifier, 4A

GBU4D Thru GBU4M



FEATURES

- UL recognition file number E320098 
- Typical IR less than 2.0 μA
- High surge current capability
- Low thermal resistance
- Compliant to RoHS
- Isolation voltage up to 2500V

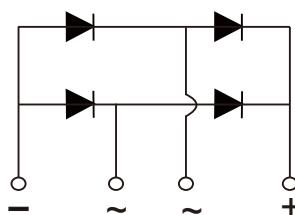


TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for big power supply, field supply for DC motor, industrial automation applications.

ADVANTAGE

- International standard package
Epoxy meets UL 94 V-0 flammability rating
- Small volume, light weight
- Small thermal resistance
- High heat-conduction rate
- Low temperature rise
- High temperature soldering guaranteed :
260°C/10 second, 2.3kg tension force
- Weight: 4.0g (0.14 ozs)



PRIMARY CHARACTERISTICS

$I_{F(AV)}$	4A
V_{RRM}	400V to 1000V
I_{FSM}	150A
I_R	5 μA
V_F	1.10V
$T_{J\max.}$	150°C

MAJOR RATINGS AND CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	GBU4				
		D	G	J	K	M
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	1000
Peak reverse non-repetitive voltage	V_{RSM}	300	500	700	900	1100
Maximum DC blocking voltage	V_{DC}	200	400	600	800	1000
Maximum average forward rectified output current, $T_c = 85^\circ\text{C}$	$I_{F(AV)}$	4				A
Peak forward surge current single sine-wave superimposed on rated load	I_{FSM}	150				A
Rating (non-repetitive, for t greater than 1 ms and less than 8.3 ms) for fusing	I^2t	93				A^2s
RMS isolation voltage from case to leads	V_{ISO}	2500				V
Operating junction storage temperature range	T_J	-40 to 150				$^\circ\text{C}$
Storage temperature range	T_{STG}	-40 to 150				$^\circ\text{C}$

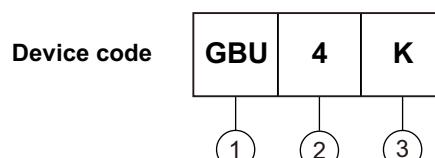
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	GBU4				
			D	G	J	K	M
Maximum instantaneous forward drop per diode	$I_F = 2\text{A}$	V_F	1.10				V
Maximum reverse DC current at rated DC blocking voltage per diod	$T_A = 25^\circ\text{C}$	I_R	5				μA
	$T_A = 150^\circ\text{C}$		500				

THERMAL AND MECHANICAL ($T_A = 25^\circ\text{C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	GBU4				
			D	G	J	K	M
Typical thermal resistance junction to case	Single-side heat dissipation, sine half wave	$R_{\theta JC}^{(1)}$	4.0				$^\circ\text{C/W}$
Mounting torque to heatsink M3 $\pm 10\%$	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.		0.8				N·m
Approximate weight			4.0				g

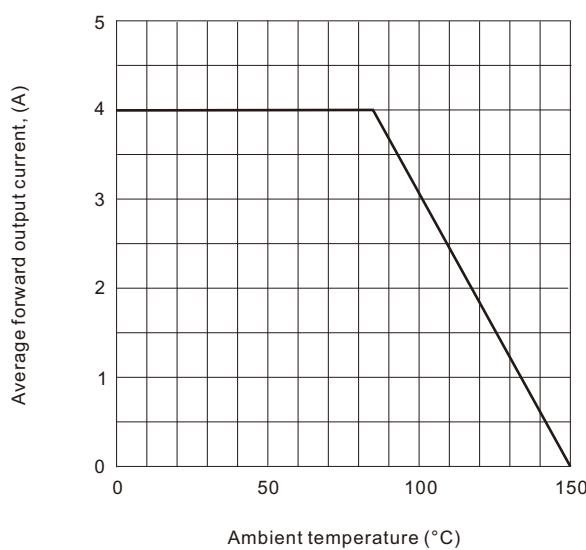
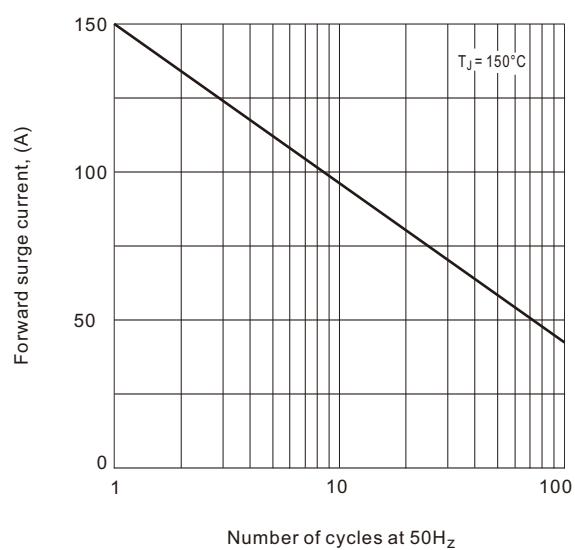
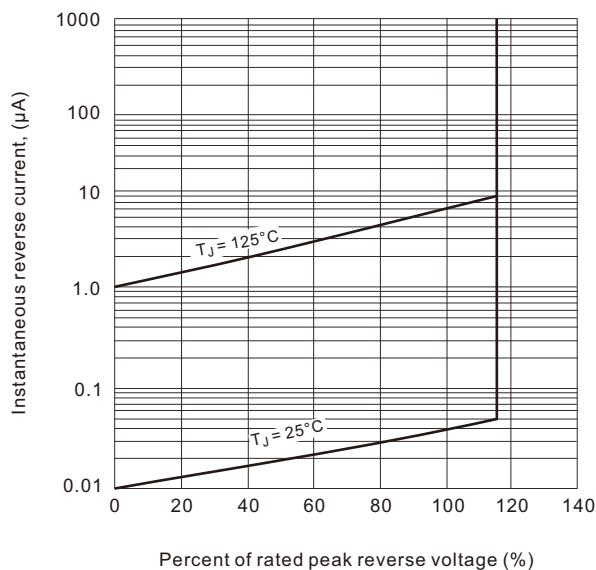
Notes

(1) With heatsink, single side heat dissipation, half sine wave.

Ordering Information Table



- [1] - Product type : "GBU" Package, 1Ø Bridge
- [2] - $I_{F(AV)}$ rating : "4" for 4A
- [3] - Voltage code : D = 200V
G = 400V
J = 600V
K = 800V
M = 1000V

Fig.1 Derating curve for output rectified current

Fig.2 Maximum non-repetitive peak forward surge current per bridge element

Fig.3 Typical reverse characteristics per bridge element

Fig.4 Typical forward characteristics per bridge element
